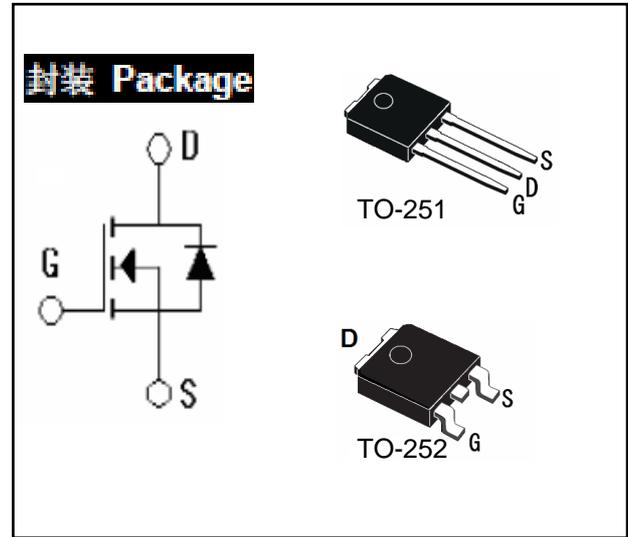


- 绝对最大额定值 (TC=25°C)
- Absolute Maximum Ratings (Tc=25°C)

参数名称 PARAMETER	符号 SYMBOL	额定值 VALUE	单位 UNIT
漏极-源极电压 Drain-Source Voltage	V <sub>DSS</sub>	600	V
连续漏极电流 Drain Current-continuous	I <sub>D</sub>	1.0	A
最大脉冲漏极电流 Drain Current-pulse	I <sub>DM</sub>	4.0	A
最高栅源电压 Gate-Source Voltage	V <sub>GSS</sub>	±30	V
耗散功率 Power Dissipation	P <sub>D</sub>	30	W
最高结温 Junction Temperature	T <sub>j</sub>	150	°C
贮存温度 Storage Temperature	T <sub>sTg</sub>	-55~+150	°C



### 电特性 (TC=25°C)

### Electronic Characteristics (Tc=25°C)

参数名称 CHARACTERISTICS	符号 SYMBOL	测试条件 TEST CONDITION	最小值 MIN	典型值 Typ	最大值 MAX	单位 UNIT
漏极-源极击穿电压 Drain-Source Voltage	B <sub>V</sub> D <sub>SS</sub>	I <sub>D</sub> =250uA; V <sub>GS</sub> =0V	600	-	-	V
零栅压下漏极漏电流 Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =600V, V <sub>GS</sub> =0V (TC=25°C)	-	-	10	uA
正向栅极体漏电流 Gate-body leakage current, forward	I <sub>GSSF</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =30V	-	-	100	nA
反向栅极体漏电流 Gate-body leakage current, reverse	I <sub>GSSR</sub>	V <sub>DS</sub> =0V, V <sub>GS</sub> =-30V	-	-	-100	nA
阈值电压 Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	2.0	-	4.0	V
静态导通电阻 Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =0.5A	-	11	15	Ω
正向跨导 Forward Transconductance	G <sub>fs</sub>	V <sub>DS</sub> =40V, I <sub>D</sub> =0.5A	-	0.8	-	S
输入电容 Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> =25V V <sub>GS</sub> =0V f=1.0MHZ	-	178	221	pF
输出电容 Output capacitance	C <sub>oss</sub>		-	19	27	pF
反向传输电容 Reverse transfer capacitance	C <sub>rss</sub>		-	3.7	4.8	pF

电特性 Electronic Characteristics

单脉冲雪崩能量 (注2) Single Pulsed Avalanche Energy	EAS	47	MJ
雪崩电流 (注1) Avalanche Current (注 1)	IAR	1.0	A
重复雪崩能量 (注1) Repetitive Avalanche Current (note1)	EAR	3.0	MJ
二极管反向恢复最大电压变化速率 (注3) Peak Diode Recovery dv/dt(note 3)	dv/dt	4.2	v/ns

开关特征 Switching Characteristics

延迟时间 Turn-On delay time	td(on)	V <sub>DD</sub> =300V, I <sub>D</sub> =1A, R <sub>G</sub> =25 Ω (note 4,5)	-	15	45	ns
上升时间 Turn-On rise time	tf		-	46	105	ns
延迟时间 Turn-Off delay time	td(off)		-	26	62	ns
下降时间 Turn-Off rise time	tf		-	37	82	ns
栅极电荷总量 Total Gate Charge	Qg	V <sub>DS</sub> =480V, I <sub>D</sub> =1A, V <sub>GS</sub> =10V (note 4,5)	-	6.1	7.2	nc
栅-源电荷 Gate-Source charge	Qgs		-	1.0	-	nc
栅-漏电荷 Gate-Drain charge	Qgd		-	3.0	-	nc

漏-源二极管特征及最大额定值 Drain-Source Diode Characteristics and Maximum Ratings

正向最大连续电流 Maximum continuous Drain-Source Diode Forward Current	I <sub>S</sub>	-	-	1.0	A	
正向最大脉冲电流 Maximum Pulsed Drain-Source Diode Forward Current	I <sub>SM</sub>	-	-	4.0	A	
正向压降 Drain-Source Diode Forward Voltage	V <sub>SDF</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =2.0A	-	-	1.0	V
反向恢复时间 Reverse recovery time	T <sub>rr</sub>	V <sub>GS</sub> =0V, I <sub>S</sub> =1.0A diF/dt=100A/us (note 4)	-	185	-	ns
反向恢复电荷 Reverse recovery charge	Q <sub>rr</sub>		-	0.51	-	μC

热特征 Thermal Characteristic

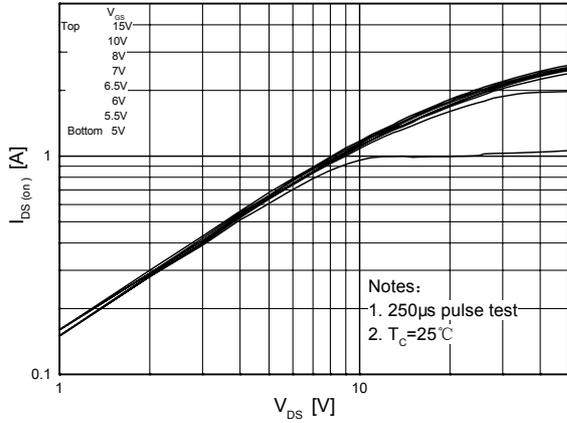
项目 Parameter	符号 Symbol	最大 (Max)	单位 (Unit)
结到管壳的热阻 Thermal Resistance, Junction to case	R <sub>th(j-c)</sub>	4.75	°C/W
结到环境的热阻 Thermal Resistance, Junction to Ambient	R <sub>th(j-a)</sub>	105	°C/W

注释:

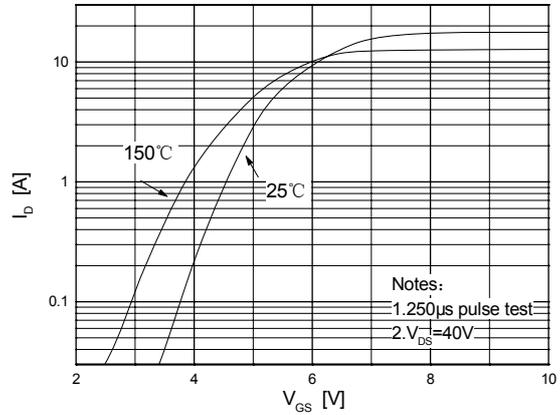
- 1: 脉冲宽度由最高结温限制
- 2: L=59mH, I<sub>AS</sub>=1.0A, V<sub>DD</sub>=50V, R<sub>G</sub>=25 Ω, 起始结温 T<sub>J</sub>=25°C
- 3: I<sub>SD</sub> ≤ 1A, di/dt ≤ 200A/μs, V<sub>DD</sub> ≤ BV<sub>DSS</sub>, 起始结温 T<sub>J</sub>=25°C
- 4: 脉冲测试: 脉冲宽度 ≤ 300μs, 占空比 ≤ 2%
- 5: 基本与工作温度无关

## 特征曲线 ELECTRICAL CHARACTERISTICS (curves)

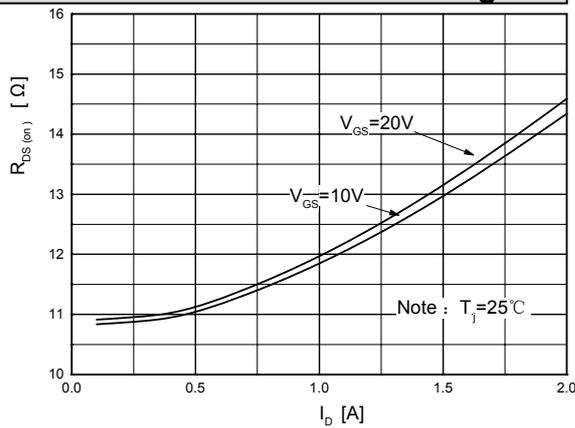
### On-Region Characteristics



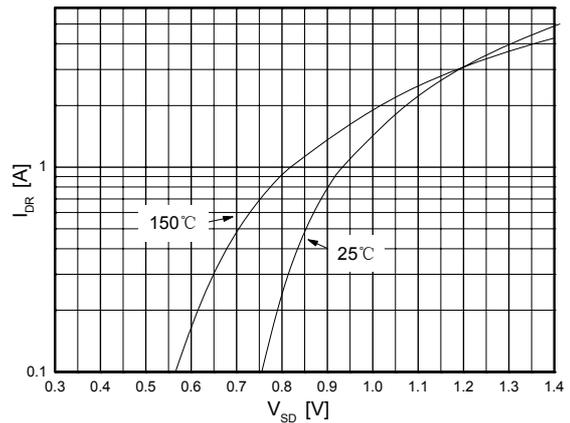
### Transfer Characteristics



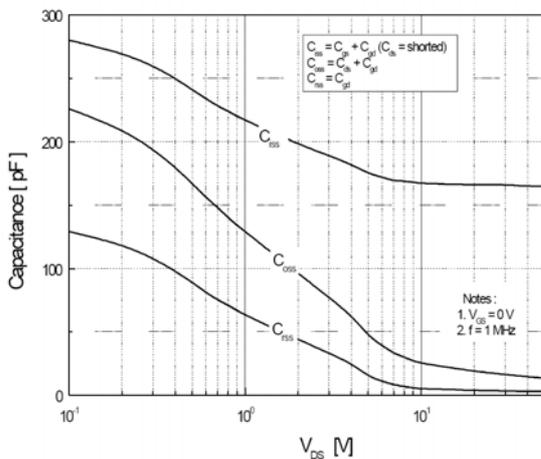
### On-Resistance Variation vs. Drain Current and Gate Voltage



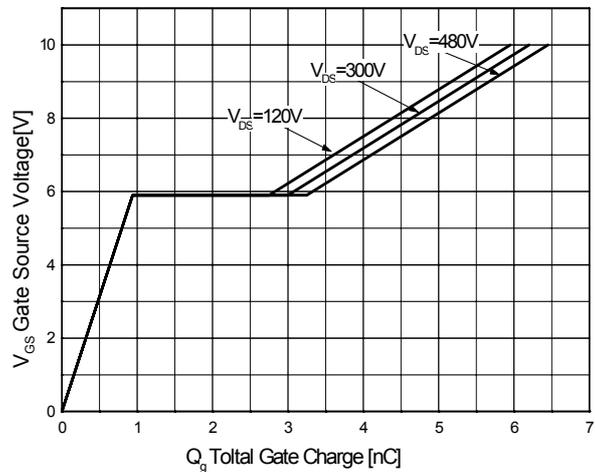
### Body Diode Forward Voltage Variation vs. Source Current and Temperature



### Capacitance Characteristics

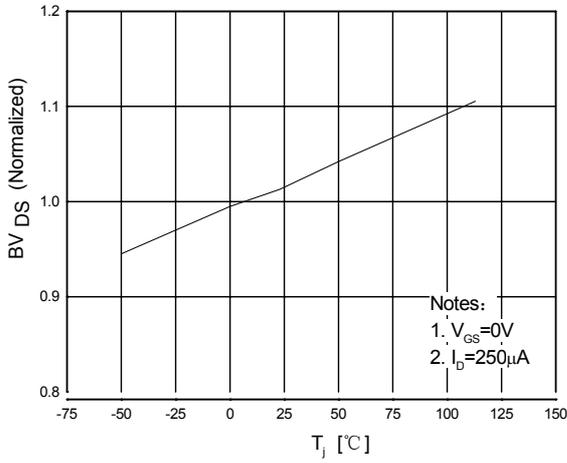


### Gate Charge Characteristics

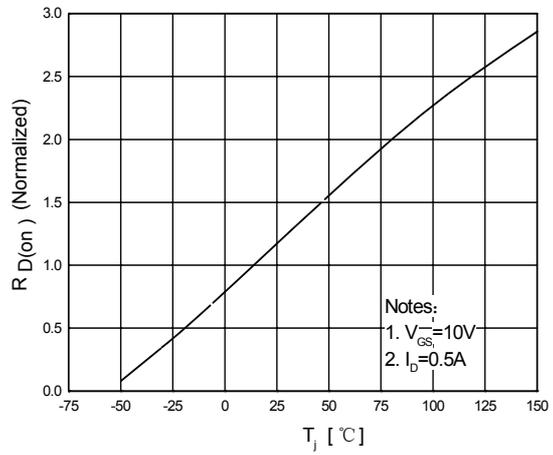


特征曲线 ELECTRICAL CHARACTERISTICS (curves)

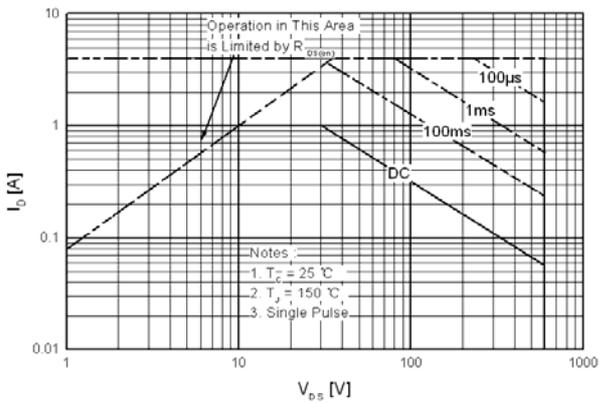
**Breakdown Voltage Variation vs. Temperature**



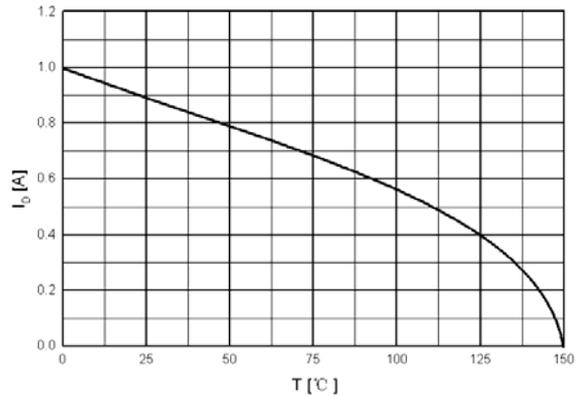
**On-Resistance Variation vs. Temperature**



**Maximum Safe Operating Area For TO-251 TO-252**



**Maximum Drain Current vs. Case Temperature**



**Transient Thermal Response Curve For TO-251 TO-252**

